

N-channel Load Switch IC

No. EA-268-210705

OUTLINE

The R5540 series are N-channel Load Switch ICs with the low supply current, Typ. 9 μ A. By using an Nch transistor as a driver transistor, the features of low on resistance and the reverse current protection at off state are realized in these ICs. The gate voltage of the N-channel transistor is supplied from the internal step-up circuit. The R5540 is an ideal switch to supply the power from the secondary power source such as the output of a step-down DC/DC to the load circuit. Since the package for the R5540 is the ultra small-sized DFN(PLP)1010-4F, high density mounting on board is possible.

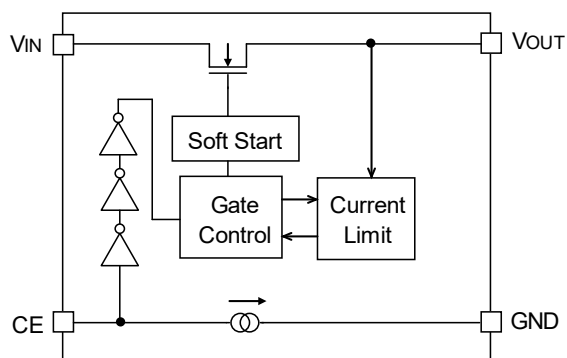
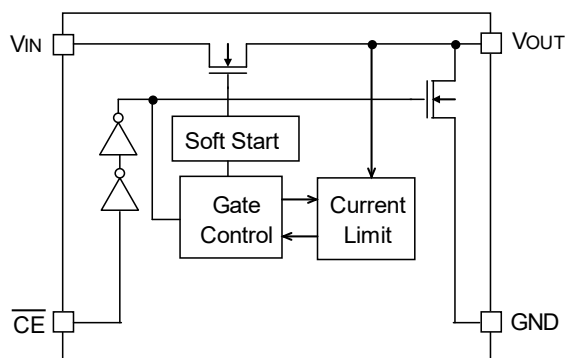
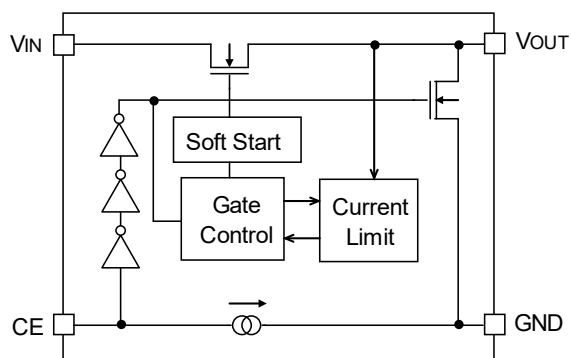
FEATURES

- Built-in an N-channel MOSFET
- Input Voltage Range 0.75V to 3.6V (Code 002)
..... 0.8V to 3.6V (Code 004)
- Supply Current at Operation ($I_{OUT}=0mA$)..... Typ. 9 μ A
- Supply Current at Standby Mode Typ. 0.1 μ A
- Switch On Resistance Typ. 120m Ω ($V_{IN}=1.2V$)
- Output Current Min. 200mA/ Min. 450mA
- Package..... DFN(PLP)1010-4F
- Built-in Over- current Sensing Circuit..... TYP. 350mA/ TYP. 700mA
- Built-in Soft-start function

APPLICATION

- For secondary power source for electrical appliances such as mobile communication equipments, cameras, VCRs and Camcorders.

BLOCK DIAGRAMS

R5540KxxxB**R5540KxxxC****R5540KxxxD**

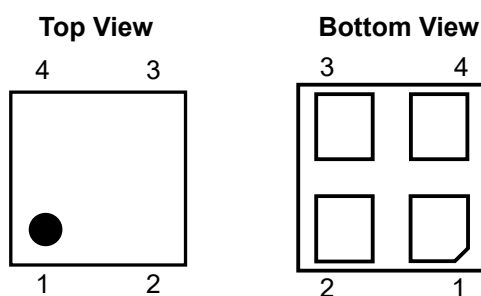
SELECTION GUIDE

The output current value, the auto-discharge function and the polarity of CE pin from "L" active, "H" active are selectable at the user's request.

Product Name	Package	Quantity per Reel	Pb Free	Halogen Free
R5540Kxxx*-TR	DFN(PLP)1010-4F	10,000pcs	Yes	Yes
xxx: The output current value can be designated by the following codes. 002: Output Current (200mA) 004: Output Current (450mA) *: Auto-discharge function at off state and the polarity of CE pin are option as follows. B: "H" active, without auto-discharge function at off state C: "L" active, with auto-discharge function at off state D: "H" active, with auto-discharge function at off state				

PIN CONFIGURATIONS

• DFN(PLP)1010-4F



PIN DESCRIPTION

● R5540K : DFN(PLP)1010-4F

Pin No	Symbol	Pin Description
1	GND	Ground Pin
2	$\overline{\text{CE}}$ / CE	Chip Enable Pin ("L" Active / "H" Active)
3	V _{IN}	Input Pin
4	V _{OUT}	Output Pin

ABSOLUTE MAXIMUM RATINGS

Symbol	Item	Rating	Unit
V _{IN}	Input Voltage	-0.3 to 5.0	V
V _{CE}	Input Voltage ($\overline{\text{CE}}$ / CE Pin)	-0.3 to 5.0	V
V _{OUT}	Output Voltage	-0.3 to 5.0	V
I _{OUT}	Output Current	Internally limited	mA
P _D	Power Dissipation (Standard Test Land Pattern)*	300	mW
T _a	Ambient Temperature	-40 to 85	°C
T _{stg}	Storage Temperature	-55 to 125	°C

*) For Power Dissipation, please refer to Power Dissipation to be described.

ABSOLUTE MAXIMUM RATINGS

Electronic and mechanical stress momentarily exceeded absolute maximum ratings may cause the permanent damages and may degrade the life time and safety for both device and system using the device in the field. The functional operation at or over these absolute maximum ratings is not assured.

RECOMMENDED OPERATING CONDITIONS (ELECTRICAL CHARACTERISTICS)

All of electronic equipment should be designed that the mounted semiconductor devices operate within the recommended operating conditions. The semiconductor devices cannot operate normally over the recommended operating conditions, even if when they are used over such conditions by momentary electronic noise or surge. And the semiconductor devices may receive serious damage when they continue to operate over the recommended operating conditions.

ELECTRICAL CHARACTERISTICS

$V_{IN} = 0.75$ to $3.60V$ (Code 002) , 0.80 to $3.60V$ (Code 004), $C_{IN} = 1\mu F$, $C_{OUT} = \text{None}$, unless otherwise noted.

The specification is surrounded by $\square$ is guaranteed by design at all temperature range, $-40^{\circ}C \leq T_a \leq 85^{\circ}C$.

R5540Kxxxx

($T_a=25^{\circ}C$)

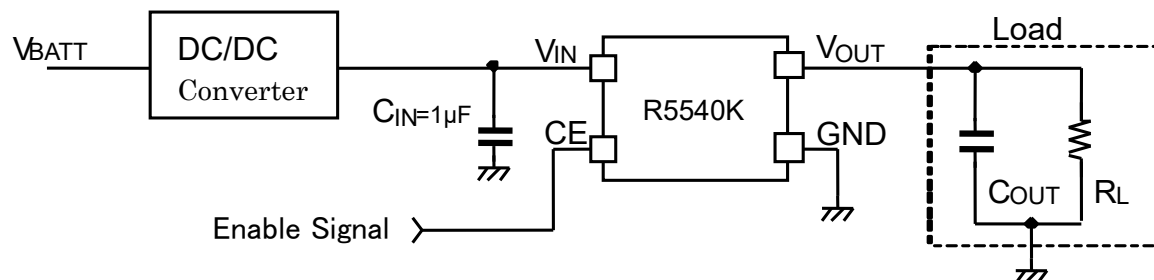
Symbol	Item	Conditions		Min.	Typ.	Max.	Unit
V _{IN}	Input Voltage	Code 002		0.75		3.60	V
		Code 004		0.80		3.60	
R _{ON}	Switch ON Resistance	Code 002	V _{IN} =1.2V, I _{OUT} =200mA		120	180	mΩ
		Code 004	V _{IN} =1.2V, I _{OUT} =450mA				
I _{OUT}	Output Current	Code 002		200			mA
I _{OUT}	Output Current	Code 004		450			
I _{SS}	Supply Current	I _{OUT} =0mA *Note1			9	40	μA
I _{standby}	Standby Current	V _{OUT} =GND V _{IN} =1.8V *Note2	Ta=25°C		0.1		μA
			Ta=85°C		5		
I _{LIM}	Current Limit	Code 002	V _{IN} =1.2V	200	350	500	mA
I _{LIM}	Current Limit	Code 004		450	700	1000	
I _{SC}	Short Current Limit	V _{IN} =1.2V, V _{OUT} =0V			50	100	mA
I _{CE}	$\overline{CE}$ Input Current	C version			0.4		μA
I _{CEPD}	CE Pull-down Current	B, D version			0.7		μA
V _{CEH}	CE Input Voltage “H”	V _{IN} =2.5V to 3.6V		1.0			V
		V _{IN} =1.0V to 2.5V		0.9			
		V _{IN} =0.75V to 1.0V		V _{IN} x 0.9			
V _{CEL}	CE Input Voltage “L”	V _{IN} =0.75V to 3.6V				0.4	V
R _{LOW}	Auto-discharge Nch Tr. ON Resistance (Version. C, D)	V _{IN} =1.2V *Note2			100		Ω
t _r	Output Rise Time	V _{IN} =1.2V, V _{OUT} =10% ~ 90% C _{OUT} =0.1μF			73		μs
t _{sc}	Short Current Response Time	V _{OUT} =0V			30		μs

All test categories were tested on the units under the pulse load condition ($T_j \approx T_a=25^{\circ}C$) except Short Current Response Time.

*Note1 $\overline{CE} = L$ for "L" active, $CE = H$ for "H" active

*Note2 $\overline{CE} = H$ for "L" active, $CE = L$ for "H" active

TYPICAL APPLICATION

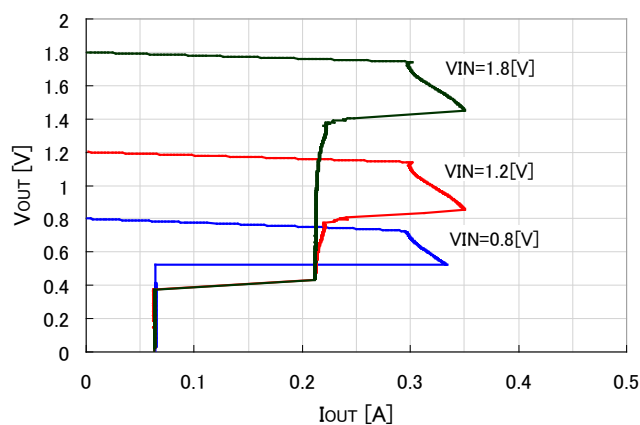


Basically, the R5540K series do not require a bypass capacitor between V_{IN} and GND, however, considering the spike noise caused by the high side inductor at current limit, use 0.1 μF or more capacitor as a bypass capacitor. More capacitance is also acceptable depending on the application.

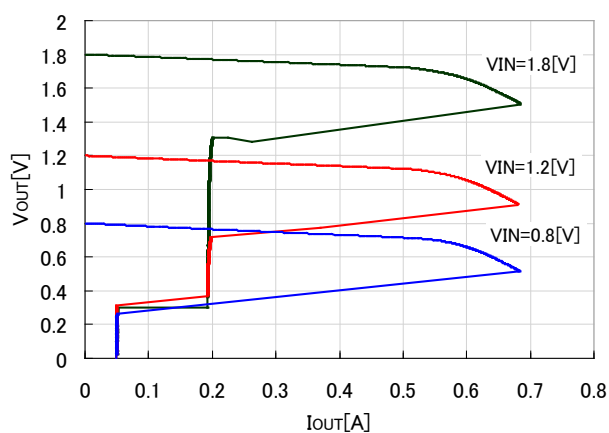
TYPICAL CHARACTERISTIC

1) Output Voltage vs. Output Current $C_{IN}=1\mu F$, $C_{OUT}=1\mu F$

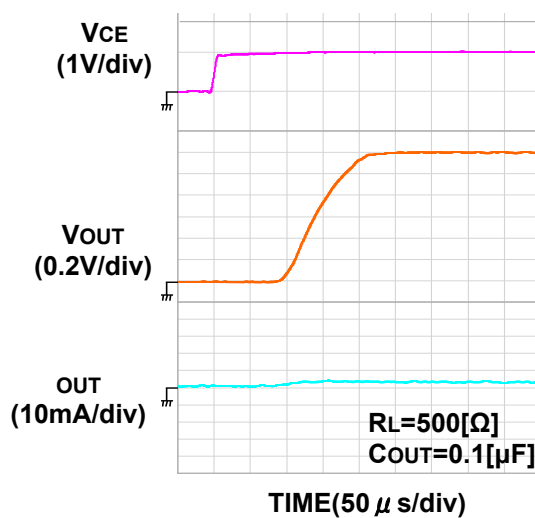
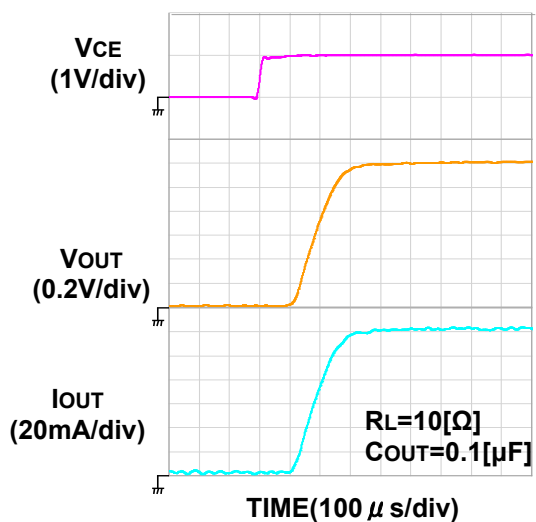
R5540K002x

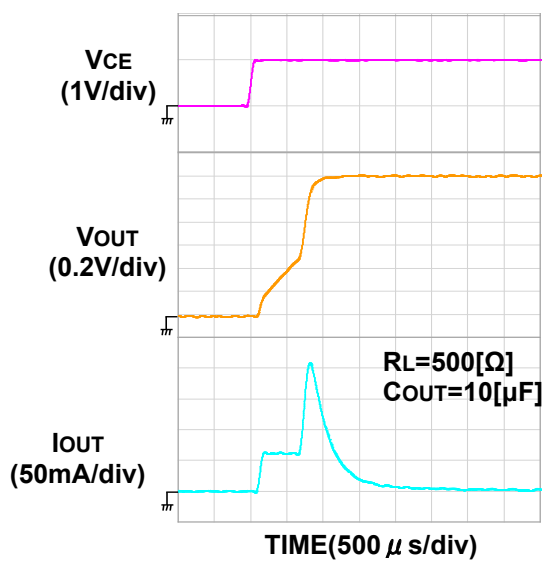
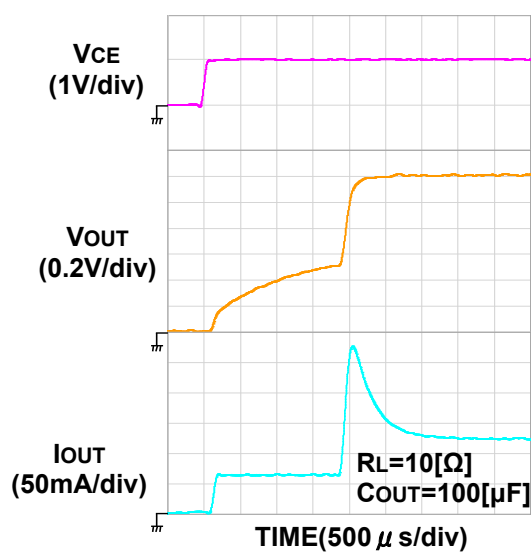
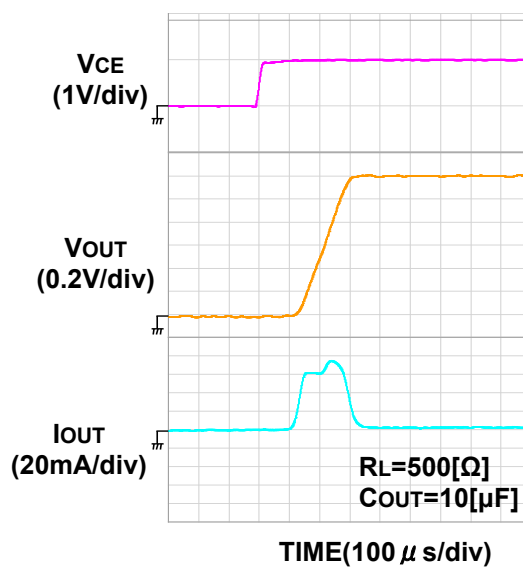
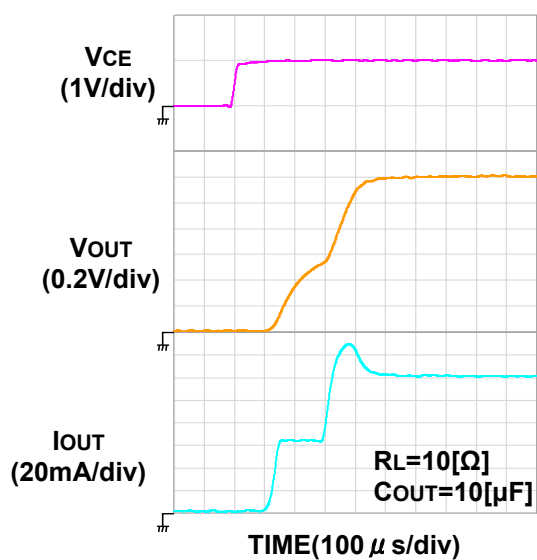
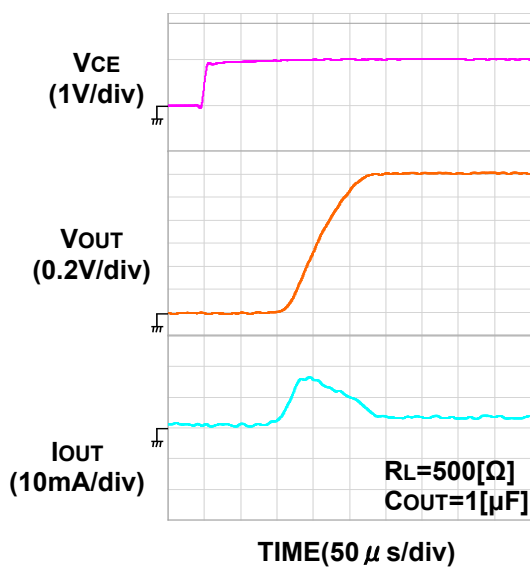
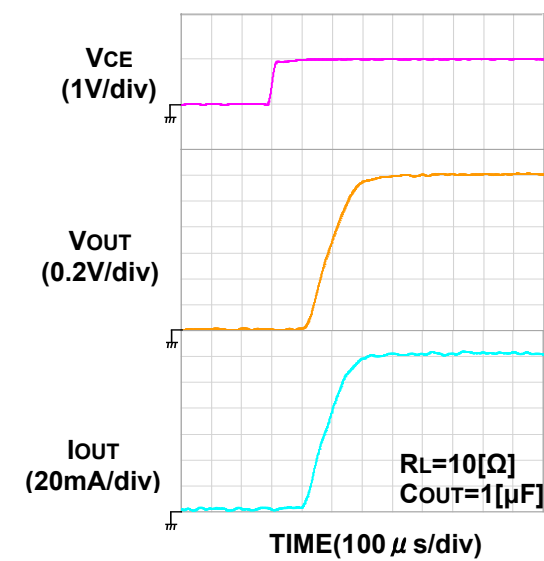


R5540K004x

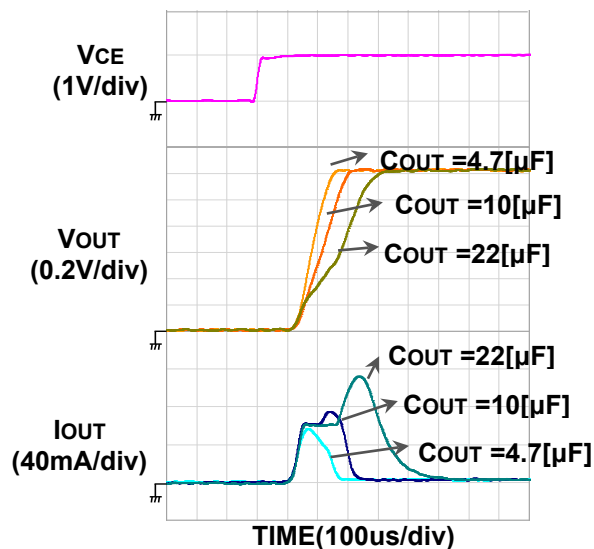


2) Turn on waveform (002x, $V_{IN}=1.2V$, $C_{IN}=1\mu F$, $T_a=25^\circ C$)

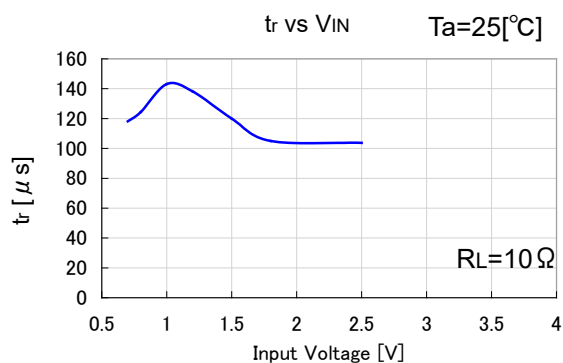




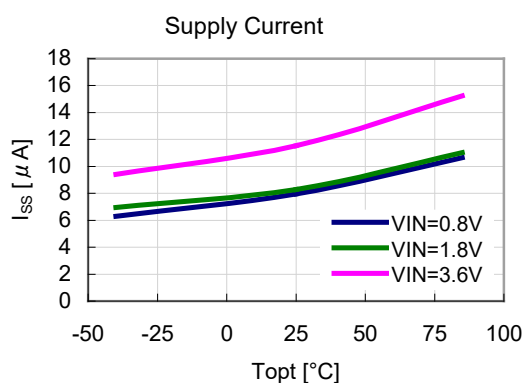
3) Inrush current vs. output capacitor (002x)



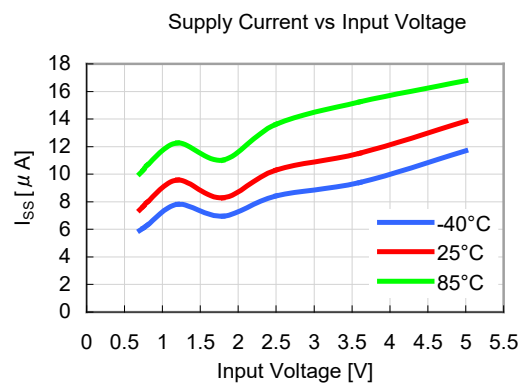
4) Input voltage vs. Turn-on speed



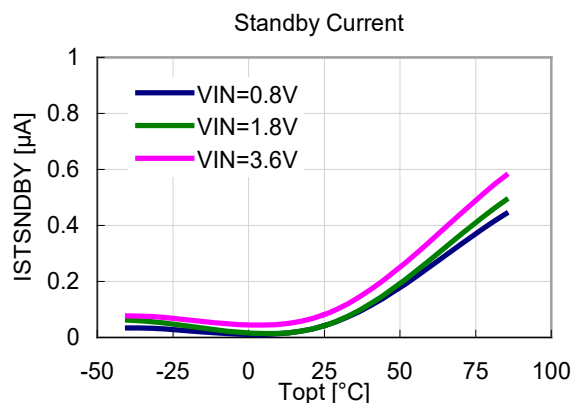
5) Supply current vs. Temperature



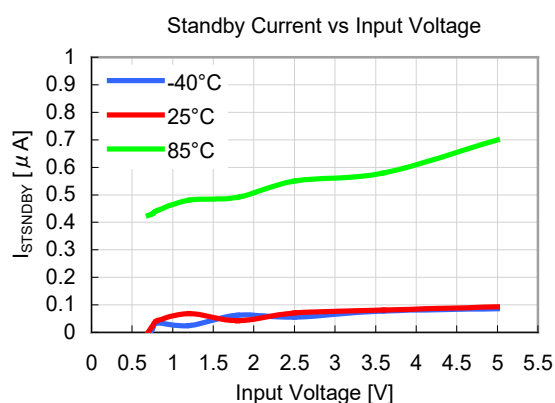
6) Standby current vs. Input voltage

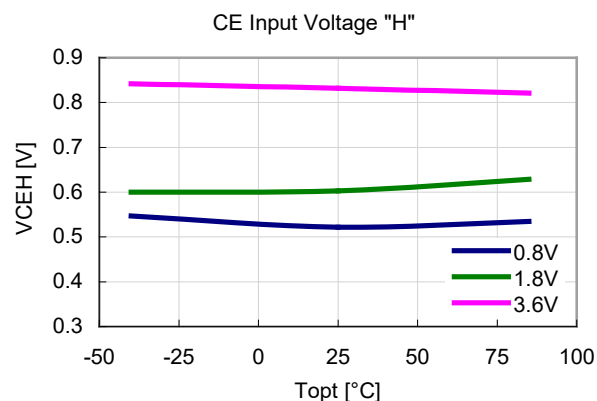
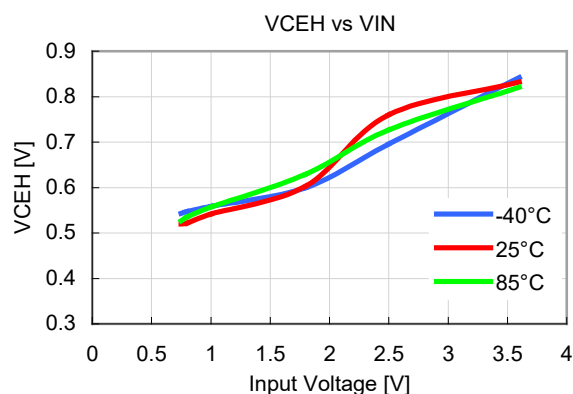
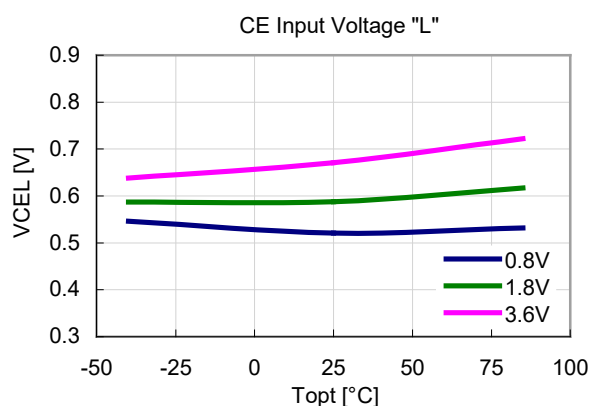
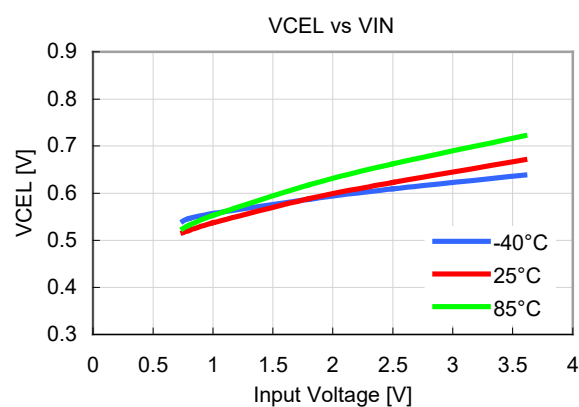
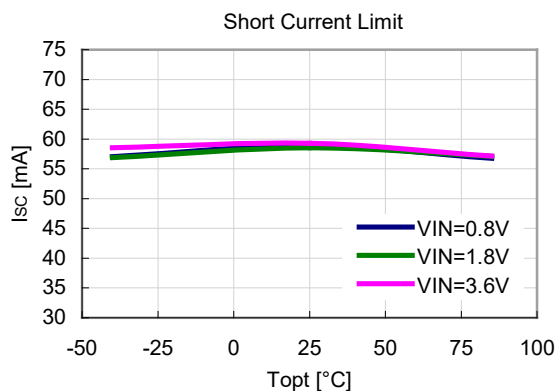
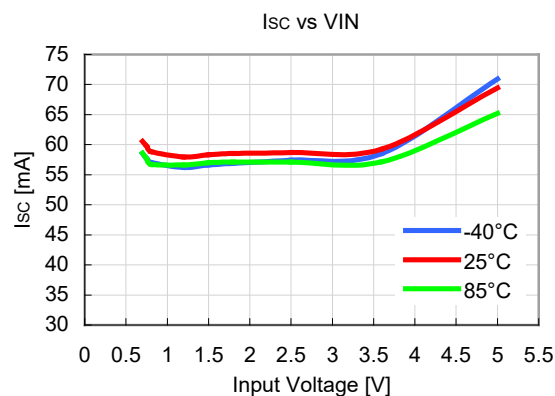
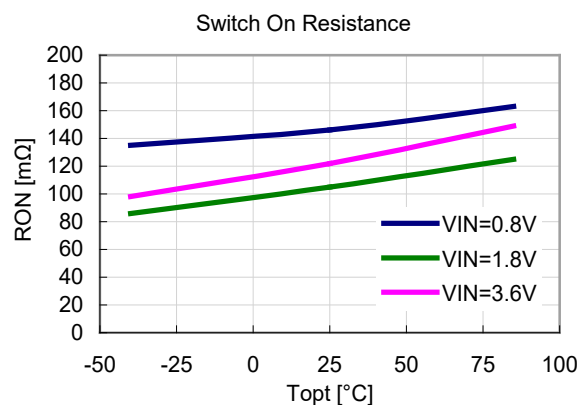
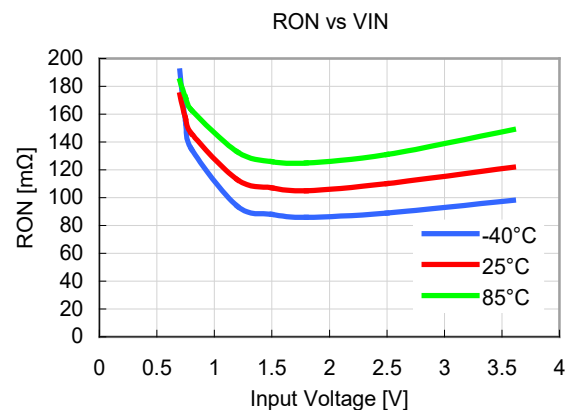


7) Standby Current vs. Temperature

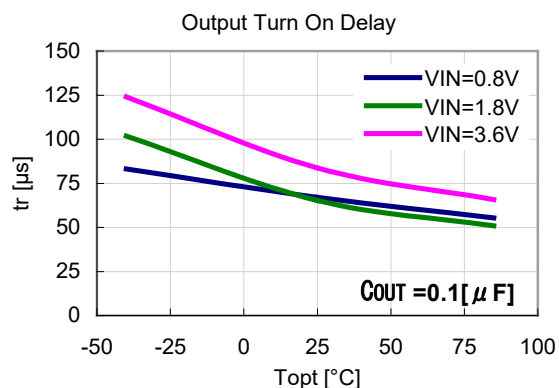


8) Standby current vs. Input voltage

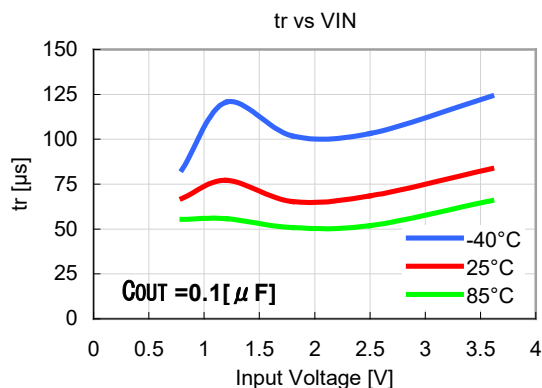


9) CE Input voltage "H" vs. Temperature**10) CE Input voltage "H" vs. VDD****11) CE Input voltage "L" vs. Temperature****12) CE Input voltage "L" vs. VDD****13) Short current limit vs. Temperature****14) Short current limit vs. Input voltage****15) Switch on resistance vs. Temperature****16) Switch on resistance vs. Input voltage**

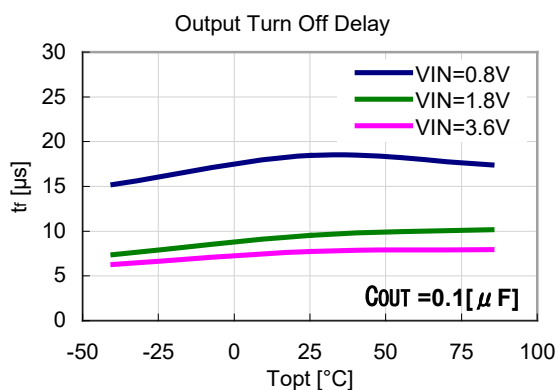
17) Output Rise time vs. Temperature



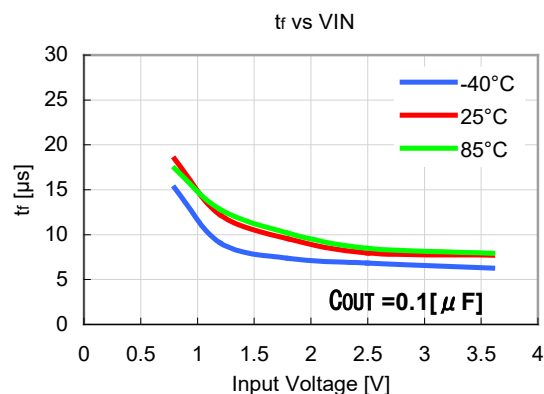
18) Output Rise time vs. Input voltage



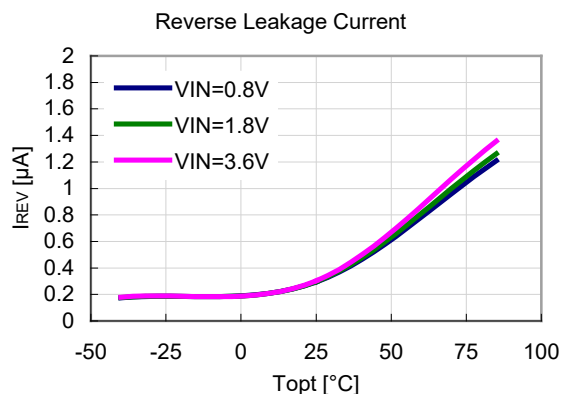
19) Output Fall time vs. Temperature



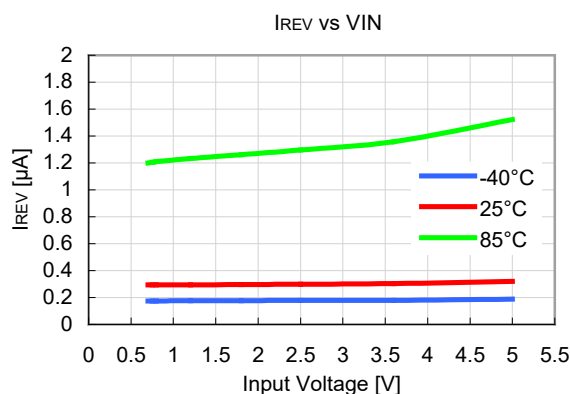
20) Output Fall time vs. Input voltage



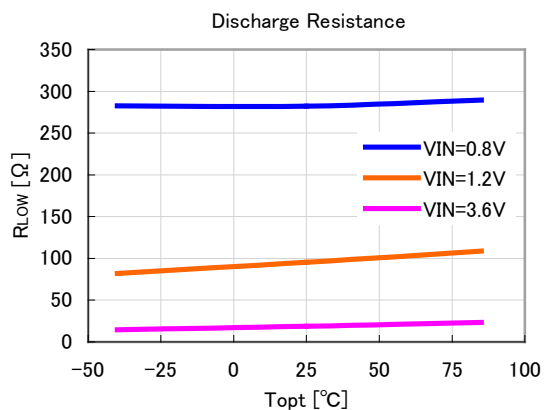
21) Reverse leakage current vs. Temperature



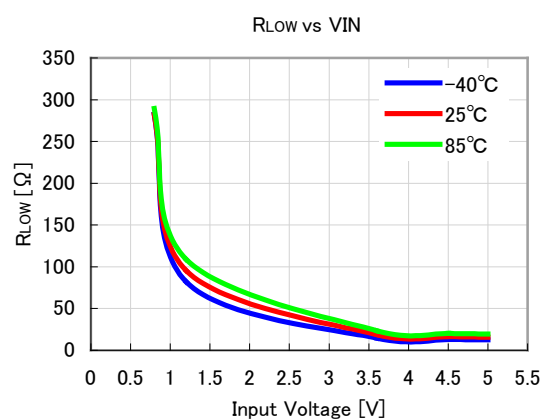
22) Reverse leakage current vs. Input voltage



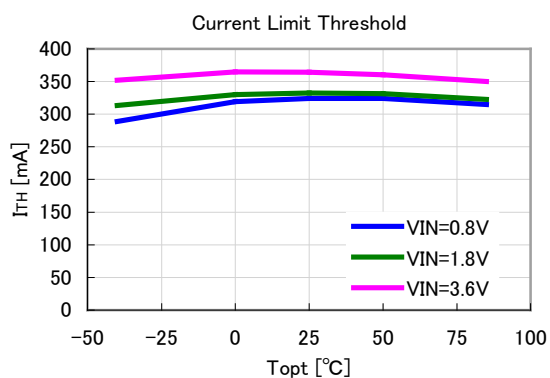
23) Discharge resistance vs. Temperature



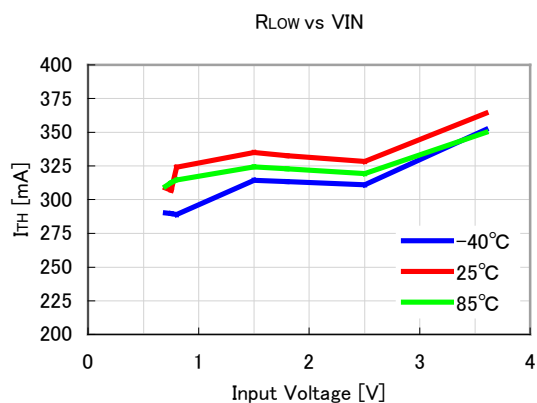
24) Discharge resistance vs. Input voltage



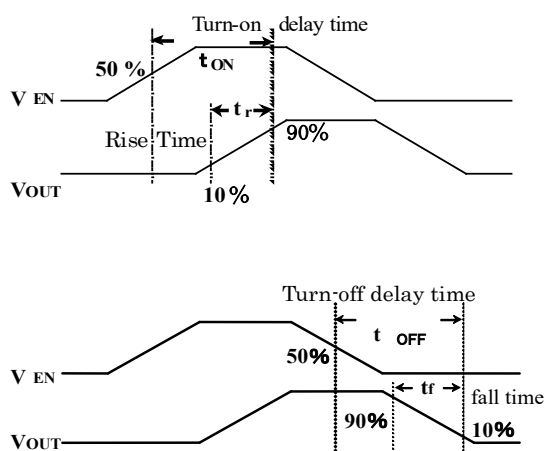
25) Current limit vs. Temperature (002x)



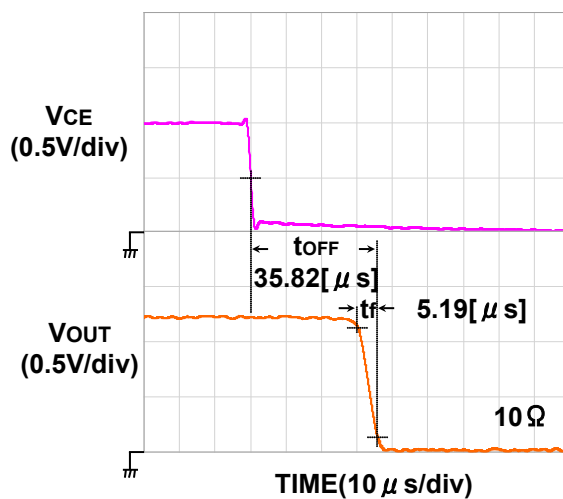
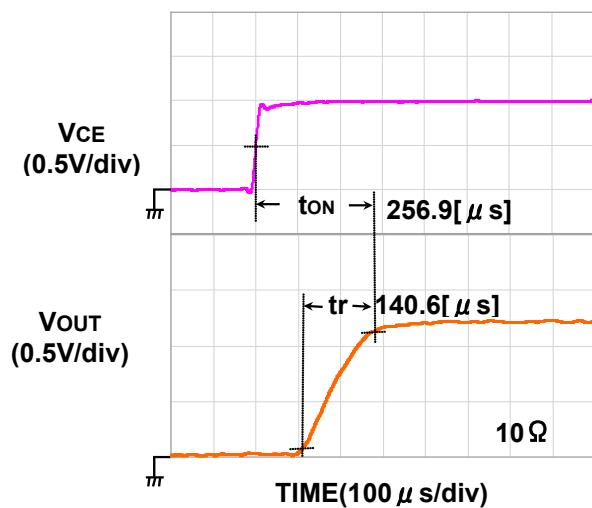
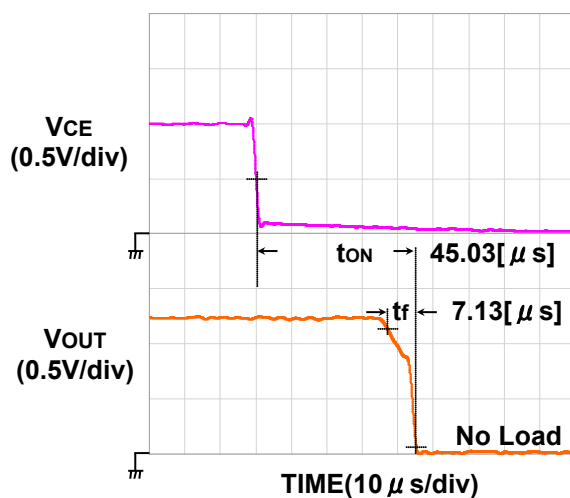
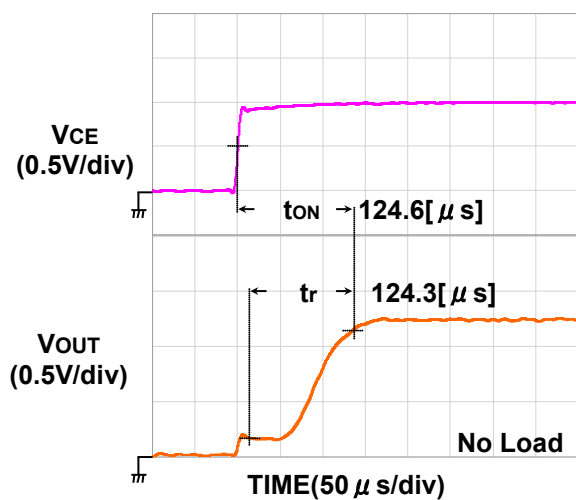
26) Current limit vs. Input voltage (002x)



TIMING CHART



Turn-on/ turn-off waveform ($V_{IN} = 1.2[V]$)



POWER DISSIPATION (DFN(PLP)1010-4F)

Power Dissipation (P_D) depends on conditions of mounting on board. This specification is based on the measurement at the condition below:

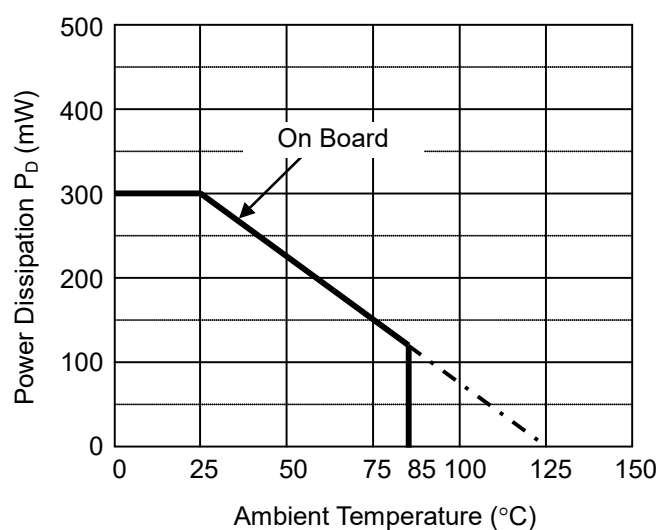
Measurement Conditions

	Standard Land Pattern
Environment	Mounting on Board (Wind velocity=0m/s)
Board Material	Glass cloth epoxy plastic (Double sided)
Board Dimensions	40mm×40mm×1.6mm
Copper Ratio	Top side: Approx. 50%, Back side: Approx. 50%
Through-holes	φ 0.54mm×24pcs

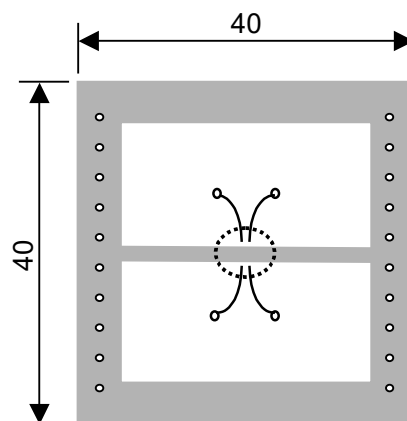
Measurement Result

($T_a=25^{\circ}\text{C}$, $T_{j\text{max}}=125^{\circ}\text{C}$)

	Standard Land Pattern
Power Dissipation	300mW
Thermal Resistance	$\theta_{ja}=(125-25^{\circ}\text{C})/0.3\text{W}=330^{\circ}\text{C/W}$
	$\theta_{jc}=48^{\circ}\text{C/W}$



Power Dissipation



Measurement Board Pattern

○ IC Mount Area (Unit : mm)



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6. We are making our continuous effort to improve the quality and reliability of our products, but semiconductor products are likely to fail with certain probability. In order to prevent any injury to persons or damages to property resulting from such failure, customers should be careful enough to incorporate safety measures in their design, such as redundancy feature, fire containment feature and fail-safe feature. We do not assume any liability or responsibility for any loss or damage arising from misuse or inappropriate use of the products.
7. Anti-radiation design is not implemented in the products described in this document.
8. The X-ray exposure can influence functions and characteristics of the products. Confirm the product functions and characteristics in the evaluation stage.
9. WLCSP products should be used in light shielded environments. The light exposure can influence functions and characteristics of the products under operation or storage.
10. There can be variation in the marking when different AOI (Automated Optical Inspection) equipment is used. In the case of recognizing the marking characteristic with AOI, please contact our sales or our distributor before attempting to use AOI.
11. Please contact our sales representatives should you have any questions or comments concerning the products or the technical information.



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